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# FGA40T65UQDF

## 650 V, 40 A Field Stop Trench IGBT

### Features

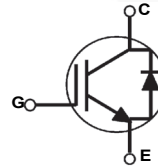
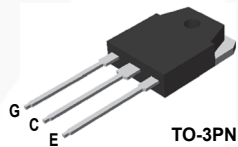
- Maximum Junction Temperature:  $T_J = 175^\circ\text{C}$
- Positive Temperature Co-efficient for Easy Parallel Operating
- High Current Capability
- Low Saturation Voltage:  $V_{CE(sat)} = 1.33\text{ V (Typ.) @ } I_C = 40\text{ A}$
- 100% of the Parts tested for  $I_{LM}(1)$
- High Input Impedance
- Fast Switching
- Tighten Parameter Distribution
- RoHS Compliant

### General Description

Using novel field stop IGBT technology, Fairchild's new series of field stop 4<sup>th</sup> generation IGBTs offer superior conduction and switching performance and easy parallel operation. This device is well suited for the resonant or soft switching application such as induction heating and MWO.

### Applications

- Induction Heating, MWO



### Absolute Maximum Ratings

Symbol	Description	FGA40T65UQDF	Unit
$V_{CES}$	Collector to Emitter Voltage	650	V
$V_{GES}$	Gate to Emitter Voltage	$\pm 20$	V
	Transient Gate to Emitter Voltage	$\pm 30$	V
$I_C$	Collector Current @ $T_C = 25^\circ\text{C}$	80	A
	Collector Current @ $T_C = 100^\circ\text{C}$	40	A
$I_{LM}(1)$	Pulsed Collector Current @ $T_C = 25^\circ\text{C}$	120	A
$I_{CM}(2)$	Pulsed Collector Current	120	A
$I_F$	Diode Forward Current @ $T_C = 25^\circ\text{C}$	40	A
	Diode Forward Current @ $T_C = 100^\circ\text{C}$	20	A
$I_{FM}$	Pulsed Diode Maximum Forward Current	60	A
$P_D$	Maximum Power Dissipation @ $T_C = 25^\circ\text{C}$	231	W
	Maximum Power Dissipation @ $T_C = 100^\circ\text{C}$	115	W
$T_J$	Operating Junction Temperature	-55 to +175	$^\circ\text{C}$
$T_{stg}$	Storage Temperature Range	-55 to +175	$^\circ\text{C}$
$T_L$	Maximum Lead Temp. for soldering Purposes, 1/8" from case for 5 seconds	300	$^\circ\text{C}$

**Notes:**

1.  $V_{CC} = 400\text{ V}$ ,  $V_{GE} = 15\text{ V}$ ,  $I_C = 120\text{ A}$ ,  $R_G = 20\ \Omega$ , Inductive Load
2. Repetitive rating: Pulse width limited by max. junction temperature

FGA40T65UQDF — 650 V, 40 A Field Stop Trench IGBT

## Thermal Characteristics

Symbol	Parameter	FGA40T65UQDF	Unit
$R_{\theta JC}$ (IGBT)	Thermal Resistance, Junction to Case, Max.	0.65	$^{\circ}\text{C}/\text{W}$
$R_{\theta JC}$ (Diode)	Thermal Resistance, Junction to Case, Max.	1.75	$^{\circ}\text{C}/\text{W}$
$R_{\theta JA}$	Thermal Resistance, Junction to Ambient, Max.	40	$^{\circ}\text{C}/\text{W}$

## Package Marking and Ordering Information

Device Marking	Device	Package	Reel Size	Tape Width	Qty per Tube
FGA40T65UQDF	FGA40T65UQDF	TO-3PN	-	-	30

## Electrical Characteristics of the IGBT $T_C = 25^{\circ}\text{C}$ unless otherwise noted

Symbol	Parameter	Test Conditions	Min.	Typ.	Max.	Unit
<b>Off Characteristics</b>						
$BV_{CES}$	Collector to Emitter Breakdown Voltage	$V_{GE} = 0\text{ V}, I_C = 1\text{ mA}$	650	-	-	V
$\Delta BV_{CES} / \Delta T_J$	Temperature Coefficient of Breakdown Voltage	$V_{GE} = 0\text{ V}, I_C = 1\text{ mA}$	-	0.52	-	$\text{V}/^{\circ}\text{C}$
$I_{CES}$	Collector Cut-Off Current	$V_{CE} = V_{CES}, V_{GE} = 0\text{ V}$	-	-	250	$\mu\text{A}$
$I_{GES}$	G-E Leakage Current	$V_{GE} = V_{GES}, V_{CE} = 0\text{ V}$	-	-	$\pm 400$	nA
<b>On Characteristics</b>						
$V_{GE(th)}$	G-E Threshold Voltage	$I_C = 40\text{ mA}, V_{CE} = V_{GE}$	2.5	4.0	5.5	V
$V_{CE(sat)}$	Collector to Emitter Saturation Voltage	$I_C = 40\text{ A}, V_{GE} = 15\text{ V}$	-	1.33	1.67	V
		$I_C = 40\text{ A}, V_{GE} = 15\text{ V}, T_C = 175^{\circ}\text{C}$	-	1.5	-	V
<b>Dynamic Characteristics</b>						
$C_{ies}$	Input Capacitance	$V_{CE} = 30\text{ V}, V_{GE} = 0\text{ V}, f = 1\text{ MHz}$	-	7309	-	pF
$C_{oes}$	Output Capacitance		-	58	-	pF
$C_{res}$	Reverse Transfer Capacitance		-	30	-	pF
<b>Switching Characteristics</b>						
$T_{d(on)}$	Turn-On Delay Time	$V_{CC} = 400\text{ V}, I_C = 40\text{ A}, R_G = 6\ \Omega, V_{GE} = 15\text{ V}, \text{Inductive Load}, T_C = 25^{\circ}\text{C}$	-	32	-	ns
$T_r$	Rise Time		-	18	-	ns
$T_{d(off)}$	Turn-Off Delay Time		-	271	-	ns
$T_f$	Fall Time		-	11	-	ns
$E_{on}$	Turn-On Switching Loss		-	989	-	$\mu\text{J}$
$E_{off}$	Turn-Off Switching Loss		-	310	-	$\mu\text{J}$
$E_{ts}$	Total Switching Loss		-	1299	-	$\mu\text{J}$
$T_{d(on)}$	Turn-On Delay Time	$V_{CC} = 400\text{ V}, I_C = 40\text{ A}, R_G = 6\ \Omega, V_{GE} = 15\text{ V}, \text{Inductive Load}, T_C = 175^{\circ}\text{C}$	-	30	-	ns
$T_r$	Rise Time		-	22	-	ns
$T_{d(off)}$	Turn-Off Delay Time		-	298	-	ns
$T_f$	Fall Time		-	16	-	ns
$E_{on}$	Turn-On Switching Loss		-	1400	-	$\mu\text{J}$
$E_{off}$	Turn-Off Switching Loss		-	553	-	$\mu\text{J}$
$E_{ts}$	Total Switching Loss		-	1953	-	$\mu\text{J}$

**Electrical Characteristics of the IGBT** (Continued)

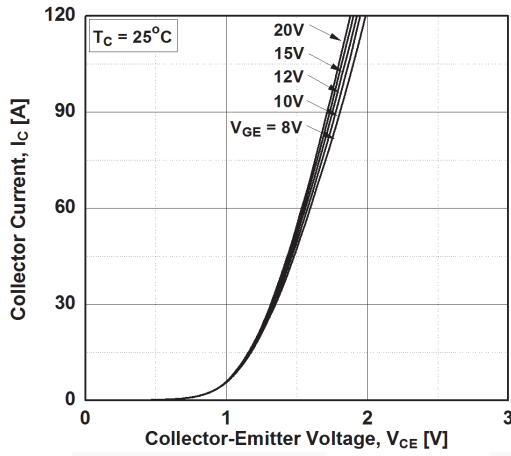
Symbol	Parameter	Test Conditions	Min.	Typ.	Max.	Unit
$Q_g$	Total Gate Charge	$V_{CE} = 400\text{ V}$ , $I_C = 40\text{ A}$ , $V_{GE} = 15\text{ V}$	-	306	-	nC
$Q_{ge}$	Gate to Emitter Charge		-	30	-	nC
$Q_{gc}$	Gate to Collector Charge		-	77	-	nC

**Electrical Characteristics of the Diode**  $T_C = 25^\circ\text{C}$  unless otherwise noted

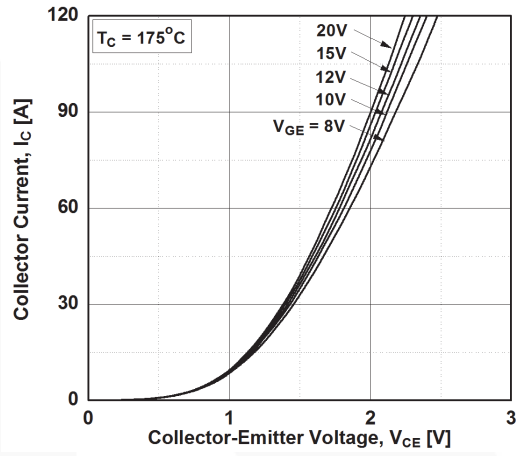
Symbol	Parameter	Test Conditions	Min.	Typ.	Max.	Unit	
$V_{FM}$	Diode Forward Voltage	$I_F = 20\text{ A}$	$T_C = 25^\circ\text{C}$	-	1.5	1.95	V
			$T_C = 175^\circ\text{C}$	-	1.39	-	
$E_{rec}$	Reverse Recovery Energy	$I_F = 20\text{ A}$ , $dI_F/dt = 200\text{ A}/\mu\text{s}$	$T_C = 175^\circ\text{C}$	-	115	-	$\mu\text{J}$
$T_{rr}$	Diode Reverse Recovery Time		$T_C = 25^\circ\text{C}$	-	89	-	ns
			$T_C = 175^\circ\text{C}$	-	251	-	
$Q_{rr}$	Diode Reverse Recovery Charge		$T_C = 25^\circ\text{C}$	-	289	-	nC
		$T_C = 175^\circ\text{C}$	-	1502	-		

## Typical Performance Characteristics

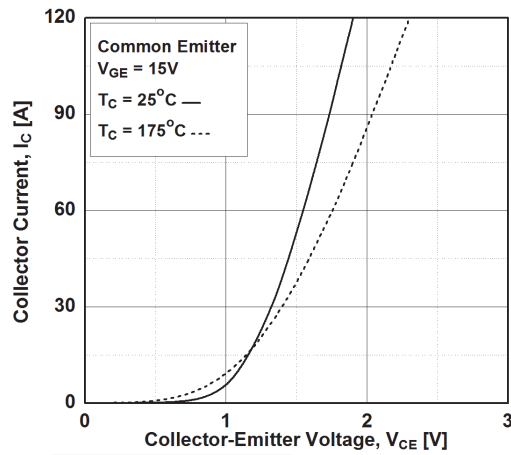
**Figure 1. Typical Output Characteristics**



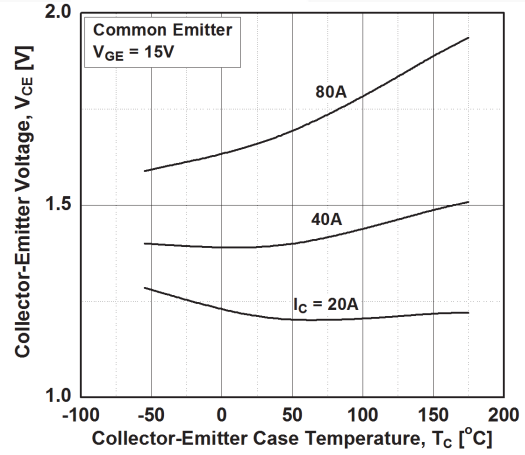
**Figure 2. Typical Output Characteristics**



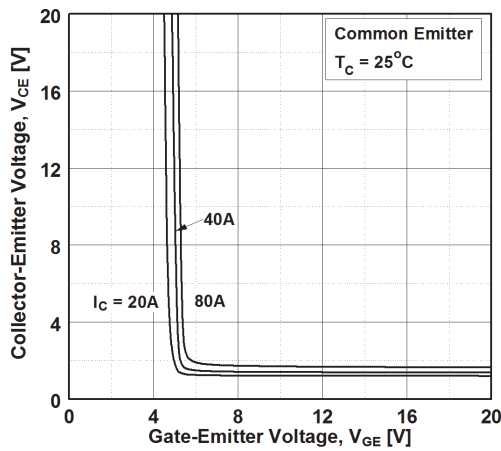
**Figure 3. Typical Saturation Voltage Characteristics**



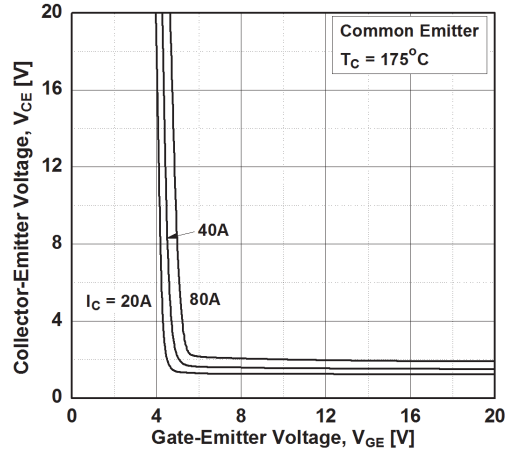
**Figure 4. Saturation Voltage vs. Case Temperature at Variant Current Level**



**Figure 5. Saturation Voltage vs. Vge**

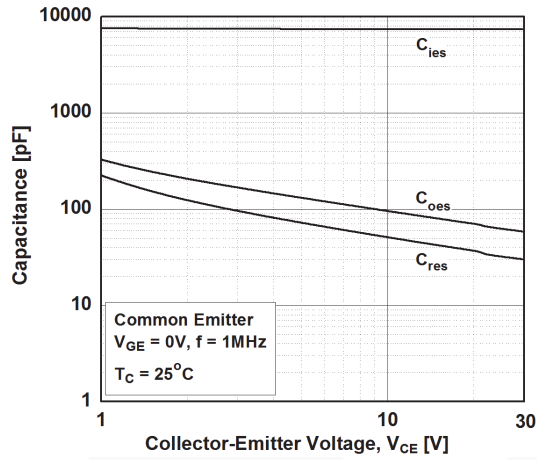


**Figure 6. Saturation Voltage vs. Vge**

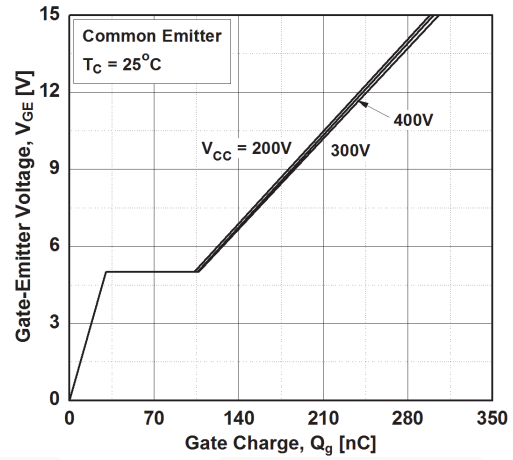


## Typical Performance Characteristics

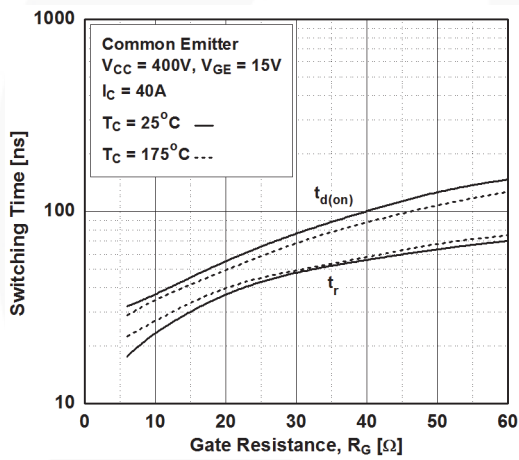
**Figure 7. Capacitance Characteristics**



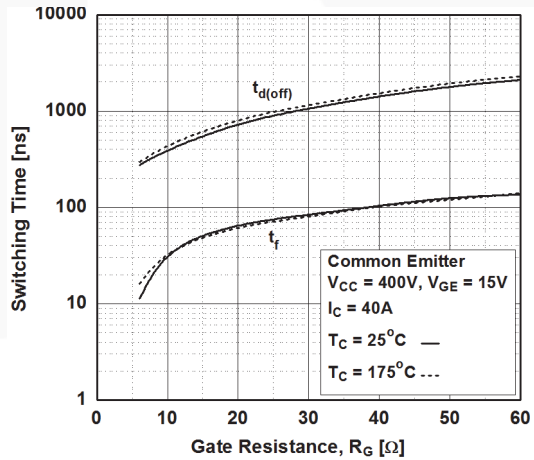
**Figure 8. Gate charge Characteristics**



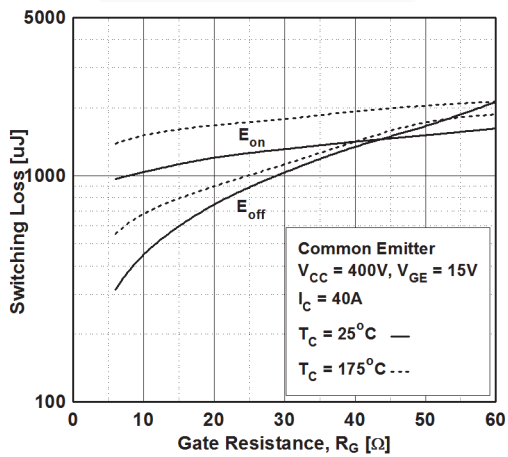
**Figure 9. Turn-on Characteristics vs. Gate Resistance**



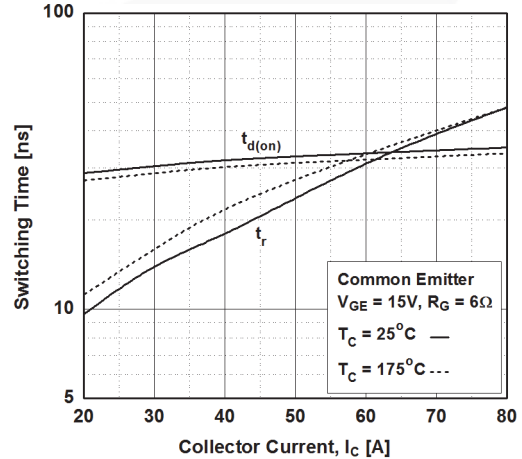
**Figure 10. Turn-off Characteristics vs. Gate Resistance**



**Figure 11. Switching Loss vs. Gate Resistance**

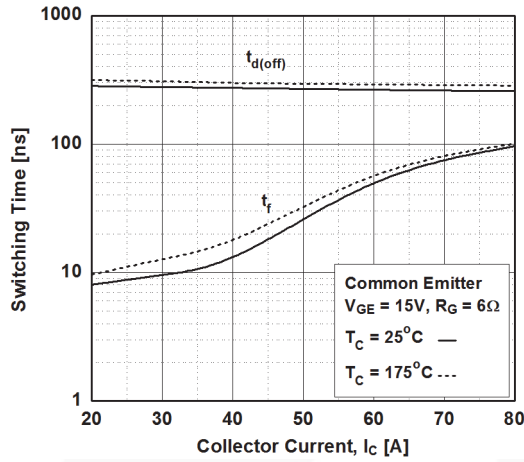


**Figure 12. Turn-on Characteristics vs. Collector Current**

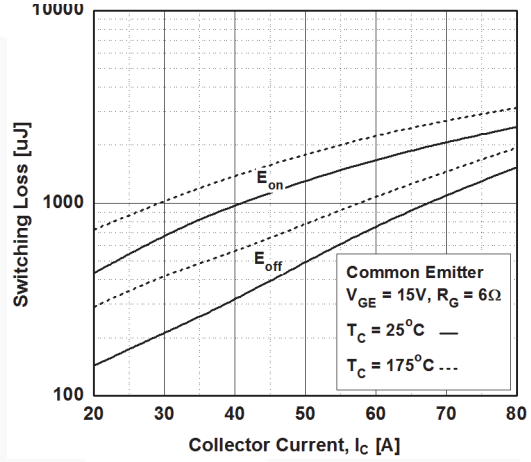


## Typical Performance Characteristics

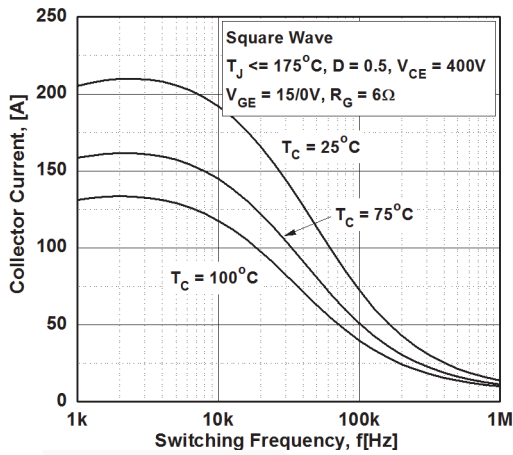
**Figure 13. Turn-off Characteristics vs. Collector Current**



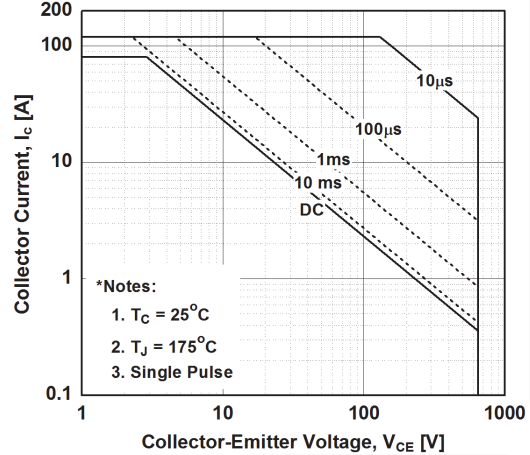
**Figure 14. Switching Loss vs. Collector Current**



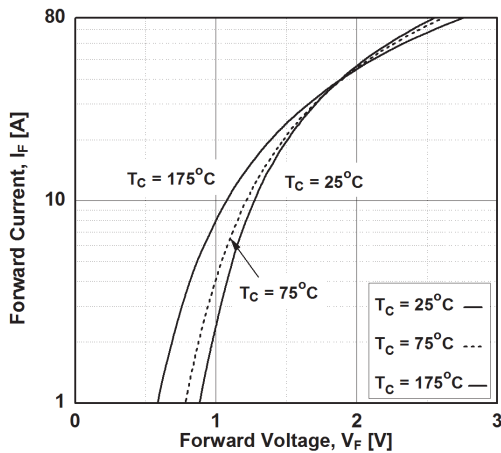
**Figure 15. Load Current Vs. Frequency**



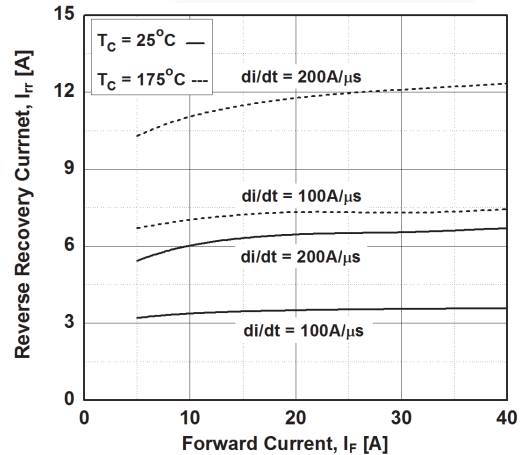
**Figure 16. SOA Characteristics**



**Figure 17. Forward Characteristics**



**Figure 18. Reverse Recovery Current**



## Typical Performance Characteristics

Figure 19. Reverse Recovery Time

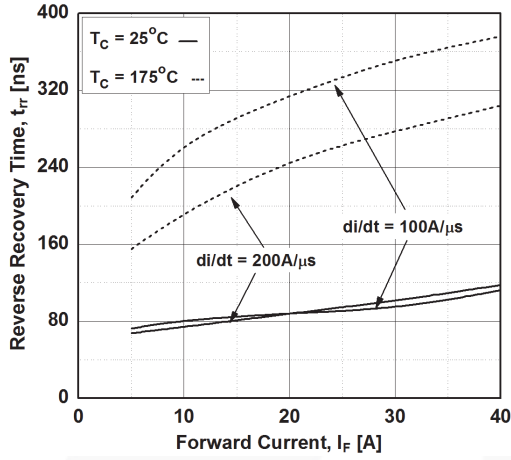


Figure 20. Stored Charge

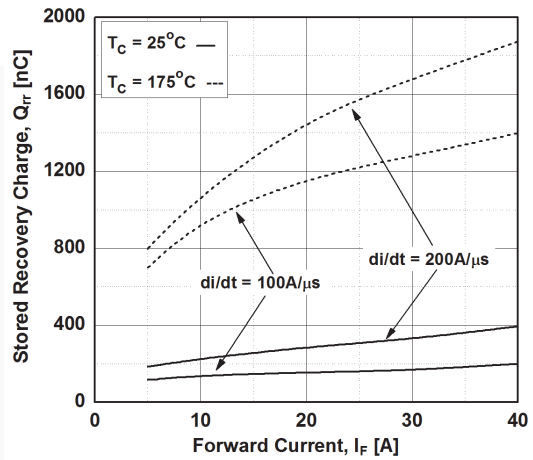


Figure 21. Transient Thermal Impedance of IGBT

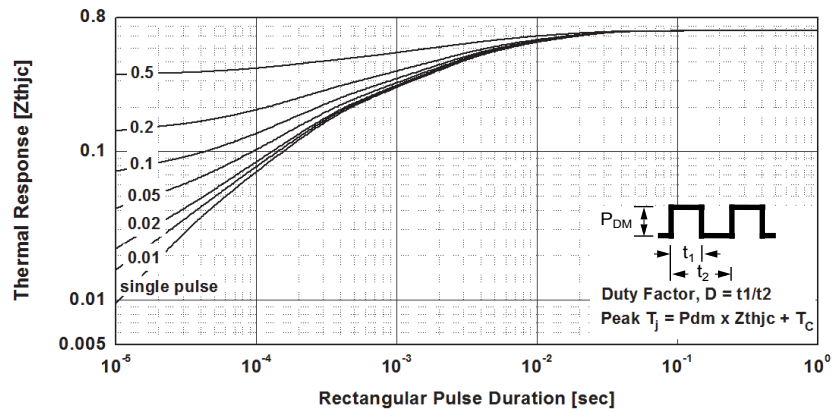
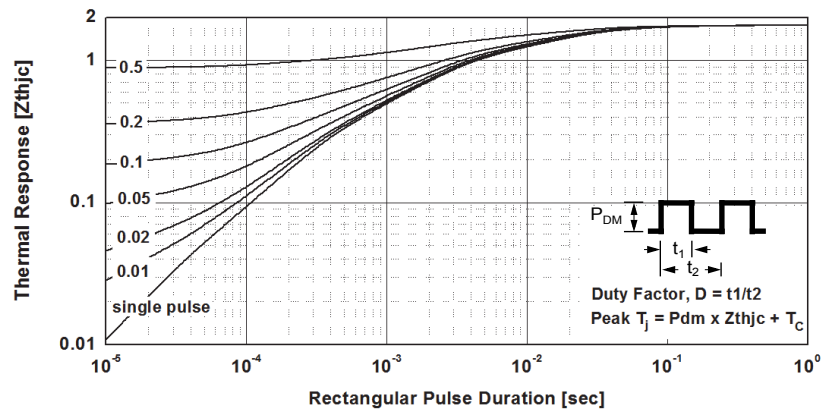
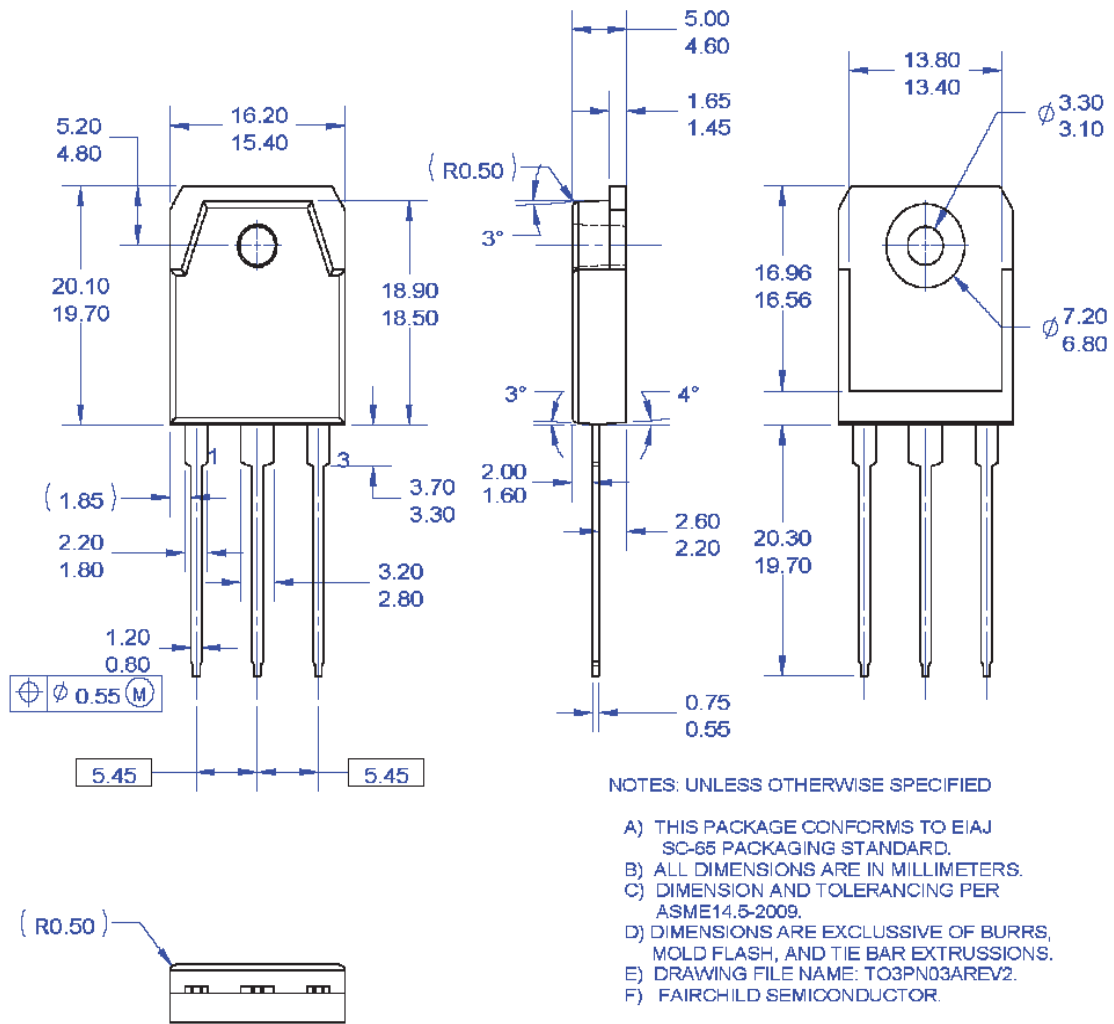


Figure 22. Transient Thermal Impedance of Diode





## Mechanical Dimensions



**Figure 23. TO3PN, 3-Lead, Plastic, EIAJ SC-65**

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